TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHC540F,TC74VHC540FW,TC74VHC540FT,TC74VHC540FK
TC74VHC541F,TC74VHC541FW,TC74VHC541FT,TC74VHC541FK

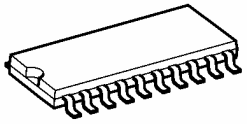
Octal Bus Buffer

TC74VHC540F/FW/FT/FK
Inverted, 3-State Outputs

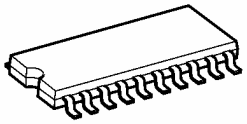
TC74VHC541F/FW/FT/FK
Non-Inverted, 3-State Outputs

Note: xxxFW (JEDEC SOP) is not available in Japan.

TC74VHC540F, TC74VHC541F

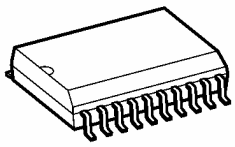


SOP20-P-300-1.27A



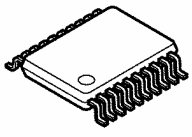
SOP20-P-300-1.27

TC74VHC540FW, TC74VHC541FW



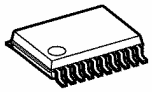
SOL20-P-300-1.27

TC74VHC540FT, TC74VHC541FT



TSSOP20-P-0044-0.65A

TC74VHC540FK, TC74VHC541FK



VSSOP20-P-0030-0.50

The TC74VHC540/TC74VHC541 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74VHC540 is an inverting type, and the TC74VHC541 is a non-inverting type.

When either $\overline{G}1$ or $\overline{G}2$ are high, the terminal outputs are in the high-impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

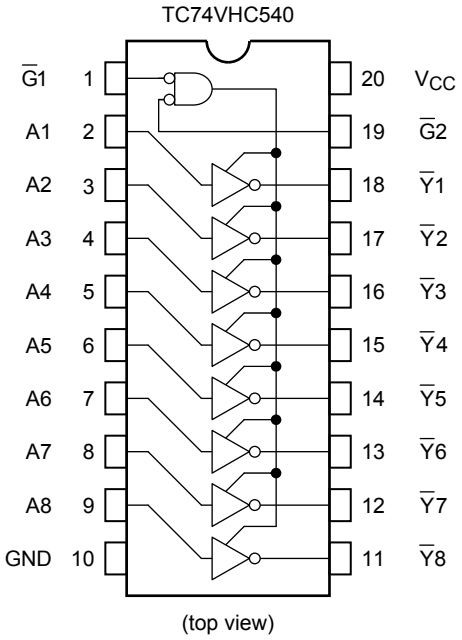
Features

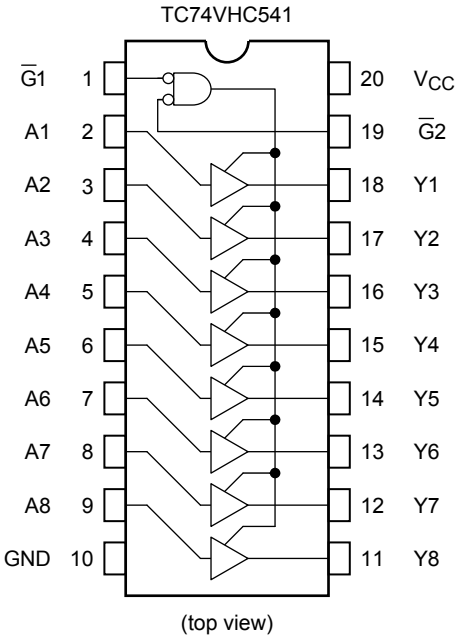
- High speed: t_{pd} = 3.7 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2 V to 5.5 V
- Low noise: V_{OLP} = 1.2 V (max)
- Pin and function compatible with 74ALS540/541

Weight

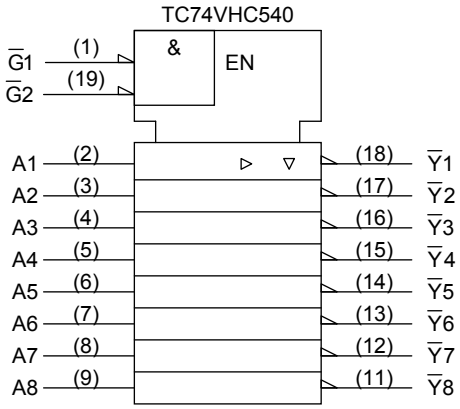
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)
VSSOP20-P-0030-0.50	: 0.03 g (typ.)

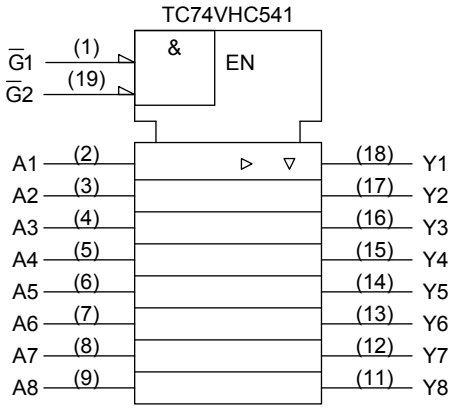
Pin Assignment





IEC Logic Symbol





Truth Table

Inputs			Outputs	
$\overline{G}1$	$\overline{G}2$	A_n	Y_n	$\overline{Y}_n$
H	X	X	Z	Z
X	H	X	Z	Z
L	L	H	H	L
L	L	L	L	H

X: Don't care

Z: High impedance

Y_n: TC74VHC541

$\overline{Y}_n$: TC74VHC540

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 ± 0.3 V) 0 to 20 (V_{CC} = 5 ± 0.5 V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				3.0 to 5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				3.0 to 5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (TC74VHC540)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	4.8	7.0	1.0	8.5	ns
				50	—	7.3	10.5	1.0	12.0	
			5.0 ± 0.5	15	—	3.7	5.0	1.0	6.0	
				50	—	5.2	7.0	1.0	8.0	
Propagation delay time (TC74VHC541)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.0	7.0	1.0	8.5	ns
				50	—	7.5	10.5	1.0	12.0	
			5.0 ± 0.5	15	—	3.5	5.0	1.0	6.0	
				50	—	5.0	7.0	1.0	8.0	
3-state output enable time	t_{pZL} t_{pZH}	R_L = 1 kΩ	3.3 ± 0.3	15	—	6.8	10.5	1.0	12.5	ns
				50	—	9.3	14.0	1.0	16.0	
			5.0 ± 0.5	15	—	4.7	7.2	1.0	8.5	
				50	—	6.2	9.2	1.0	10.5	
3-state output disable time	t_{pLZ} t_{pHZ}	R_L = 1 kΩ	3.3 ± 0.3	50	—	11.2	15.4	1.0	17.5	ns
			5.0 ± 0.5	50	—	6.0	8.8	1.0	10.0	
Output to output skew	t_{osHL} t_{osLH}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance (Note 2)	C_{PD}	TC74VHC540			—	17	—	—	—	pF
		TC74VHC541			—	18	—	—	—	

Note 1: Parameter guaranteed by design.

$t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

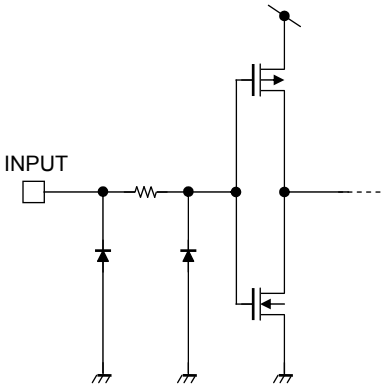
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

Noise Characteristics (input: $t_r = t_f = 3$ ns) (Note)

Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.7 (0.9)	1.0 (1.2)	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.7 (−0.9)	−1.0 (−1.2)	V
Minimum high level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

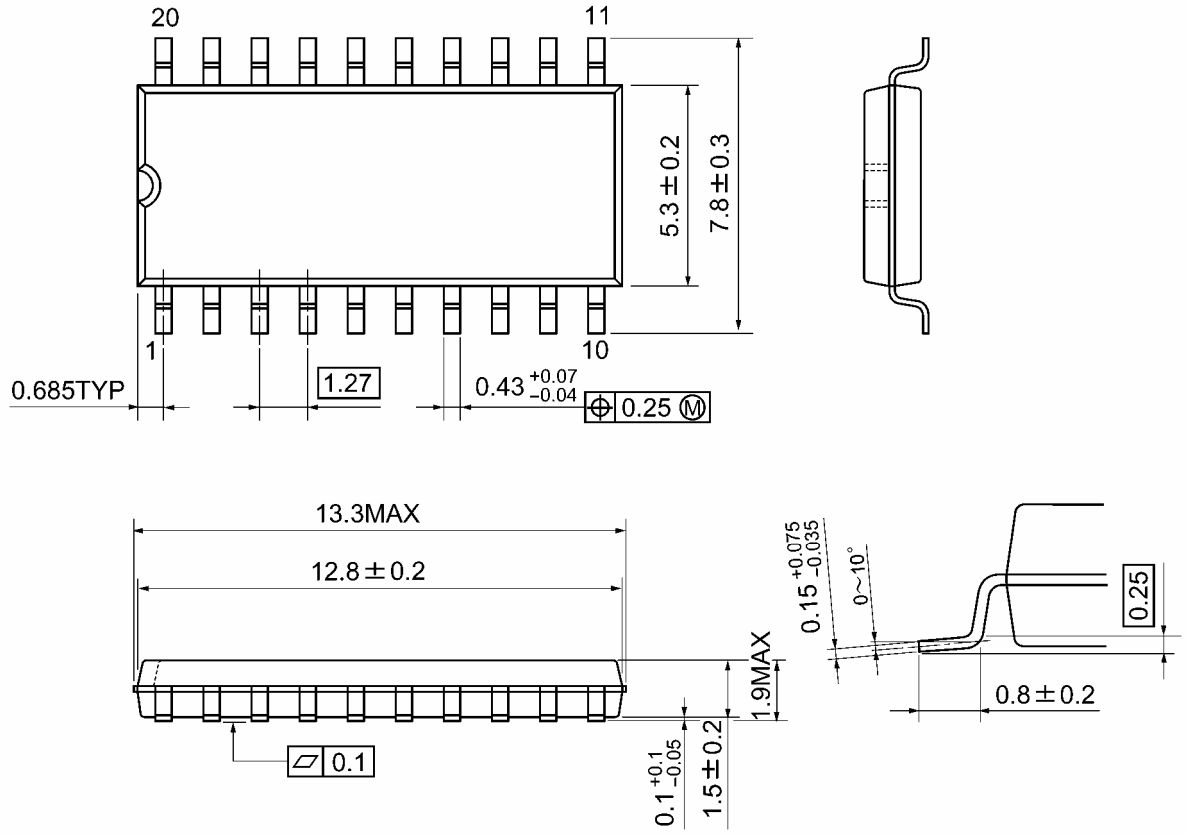
Note: The value in ( ) only applies to JEDEC SOP (FW) devices.

Input Equivalent Circuit



Package Dimensions

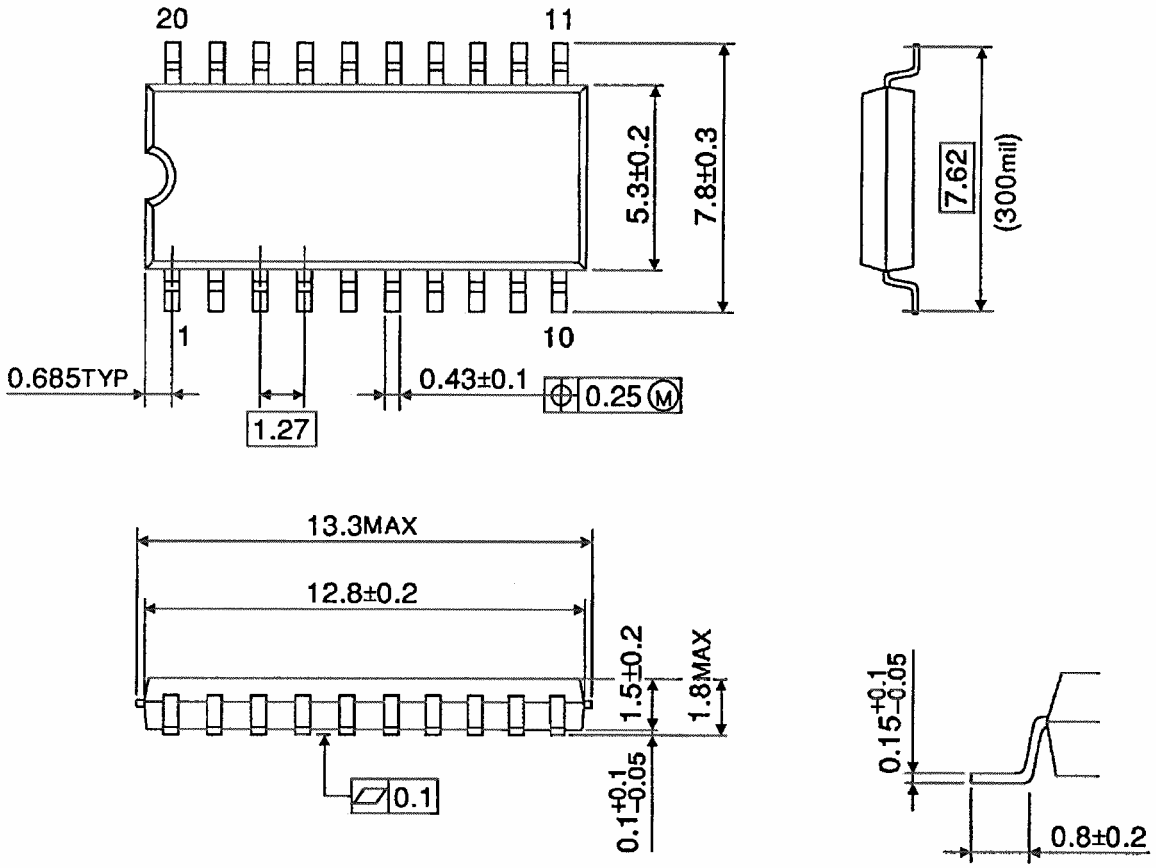
SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

Package Dimensions

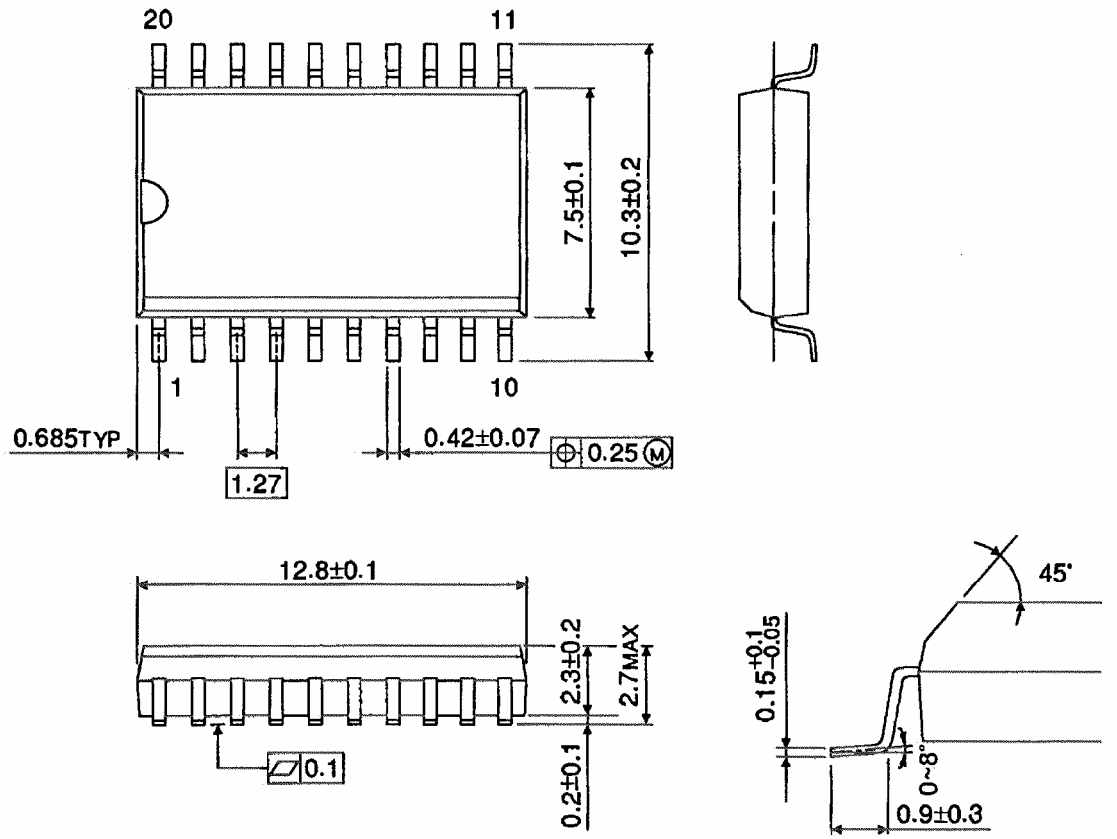
SOP20-P-300-1.27 Unit : mm



Weight: 0.22 g (typ.)

Package Dimensions (Note)

SOL20-P-300-1.27 Unit : mm

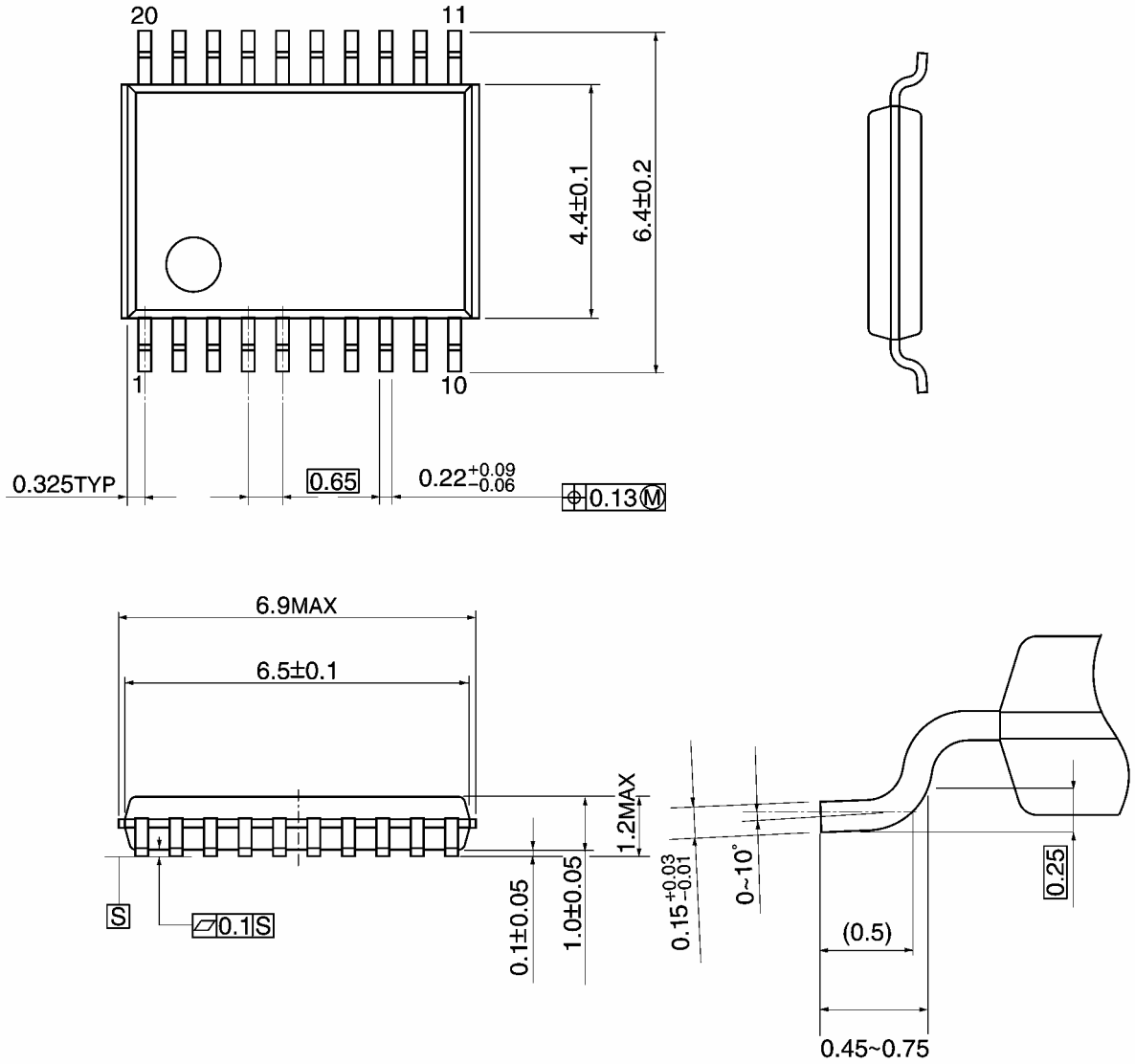


Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Package Dimensions

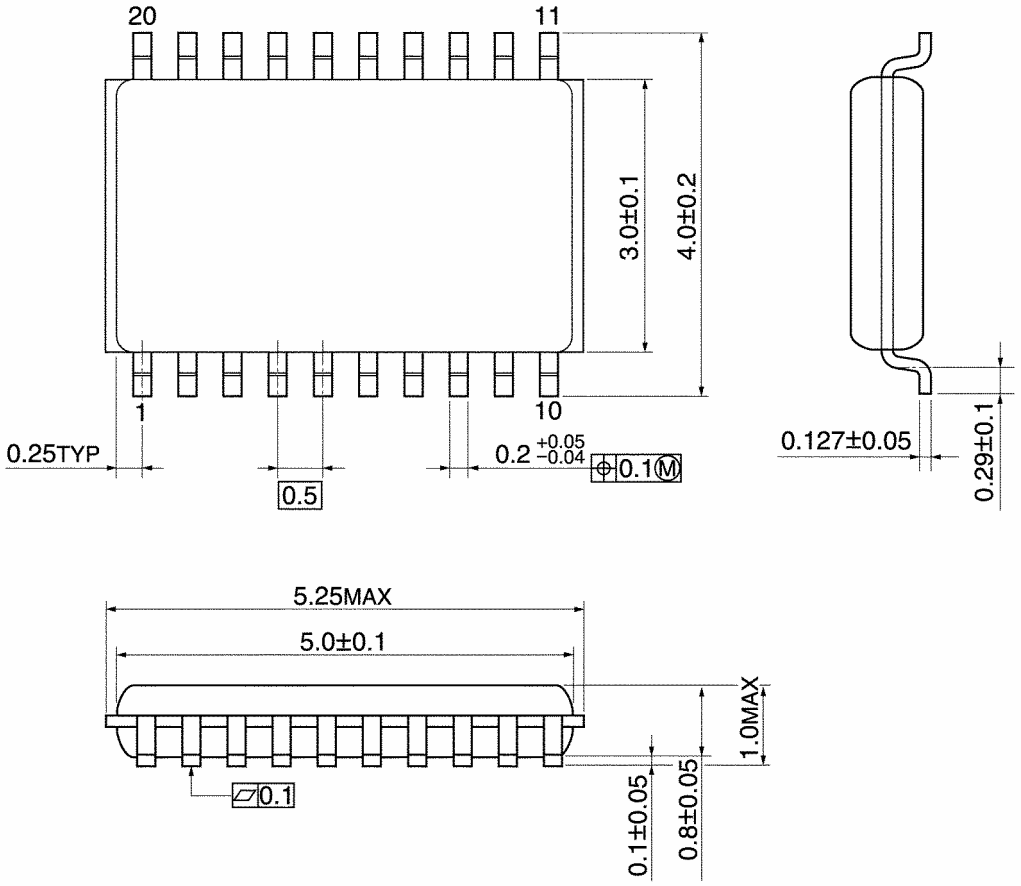
TSSOP20-P-0044-0.65A Unit: mm



Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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20070701-EN

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